

# HA-5102/883

## Dual, Low Noise, High Performance **Operational Amplifier**

June 1994

#### Features

- . This Circuit is Processed in Accordance to MIL-STD-883 and is Fully Conformant Under the Provisions of Paragraph 1.2.1.
- Low input Noise Voltage Density at 1kHz. . 6nV/√Hz (Max) 4.3nV/√Hz (Typ)
- High Slew Rate................................. 1V/μs (Min) 3V/μs (Typ)
- Unity Gain Bandwidth . . . . . . . . . . 8MHz(Typ)
- High Open Loop Gain (Full Temp) . . . . . 100kV/V (Min) 250kV/V (Typ)
- High CMRR, PSRR (Full Temp)......86dB (Min) 100dB (Typ)
- Low Offset Voltage Drift ...... 3μV/°C (Typ)
- No Crossover Distortion
- Standard Dual Pinout

#### Applications

- · High Quality Audio Preamplifiers
- High Q Active Filters
- Low Noise Function Generators
- . Low Distortion Oscillators
- Low Noise Comparators

#### Description

Low noise and high performance are key words describing the unity gain stable HA-5102/883. This general purpose dual amplifier offers an array of dynamic specifications including 1V/µs slew rate (min), A<sub>VCl</sub> ≥ 1, and 8MHz bandwidth (typ). Complementing these outstanding parameters is a very low noise specification of 4.3nV/\(\frac{1}{12}\) at 1kHz (typ), 6nV/√Hz (max).

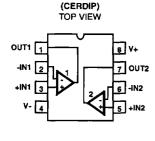
Fabricated using the Harris standard high frequency D.I. process, these operational amplifiers also offer excellent input specifications such as 2.5mV (max) offset voltage and 75nA (max) offset current. Complementing these specifications are 100dB (min) open loop gain and 60dB channel separation (min). Economically, the HA-5102/883 also consumes a very moderate amount of supply power 180mW/ package.

This impressive combination of features make this amplifier ideally suited for designs ranging from audio amplifiers and active filters to the most demanding signal conditioning and instrumentation circuits.

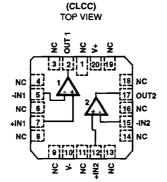
### Ordering Information

PART NUMBER	TEMPERATURE RANGE	PACKAGE
HA2-5102/883	-55°C to +125°C	8 Pin Can
HA4-5102/883	-55°C to +125°C	20 Lead Ceramic LCC
HA7-5102/883	-55°C to +125°C	8 Lead CerDIP

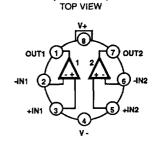
#### **Pinouts**



HA-5102/883



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(METAL CAN)

CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper I.C. Handling Procedures. Copyright @ Harris Corporation 1994 3-109

Spec Number 511019-883 File Number 3709

#### Specifications HA-5102/883

#### Thermal Information Absolute Maximum Ratings Thermal Resistance Differential Input Voltage......7V CerDIP Package ...... 115°C/W 28°C/W Voltage at Either Input Terminal . . . . . . . . . . . . V+ to V-15°C/W Peak Output Current ...... Indefinite Metal Can Package . . . . . . . . . . . . . . . . . 155°C/W (One Amplifier Shorted to Ground) Package Power Dissipation Limit at +75°C for T<sub>J</sub> ≤ +175°C CerDIP Package ......870mW Junction Temperature (T<sub>J</sub>) . . . . . . . . . . . . . . . . . . +175°C Storage Temperature Range . . . . . . . . . . -65°C to +150°C Ceramic LCC Package ......1.54W Metal Can Package ...... 645mW ESD Rating.....<2000V Lead Temperature (Soldering 10s).....+300°C Package Power Dissipation Derating Factor Above +75°C CerDIP Package ......8.7mW/°C Ceramic LCC Package ......15.4mW/°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### **Operating Conditions**

#### TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS

Device Tested at:  $V_{SUPPLY} = \pm 15V$ ,  $R_{SOURCE} = 100\Omega$ ,  $R_{LOAD} = 500k\Omega$ ,  $V_{OUT} = 0V$ , Unless Otherwise Specified.

	SYMBOL	CONDITIONS	GROUP A SUBGROUPS	TEMPERATURE	LIMITS		
PARAMETERS					MIN	MAX	UNITS
Input Offset Voltage	V <sub>IO</sub>	V <sub>CM</sub> = 0V	1	+25°C	-2.0	2.0	mV
			2, 3	+125°C, -55°C	-2.5	2.5	mV
Input Bias Current	+l <sub>B</sub>	V <sub>CM</sub> = 0V,	1	+25°C	-200	200	nA
		$+R_S = 10k\Omega$ , $-R_S = 100\Omega$	2, 3	+125°C, -55°C	-325	325	nA
	-l <sub>B</sub>	V <sub>CM</sub> = 0V,	1	+25°C	-200	200	nA
		$+R_S = 100\Omega$ , $-R_S = 10k\Omega$	2, 3	+125°C, -55°C	-325	325	nA
Input Offset Current	lio	V <sub>CM</sub> = 0V,	1	+25°C	-75	75	nA
		$+R_S = 10k\Omega$ , $-R_S = 10k\Omega$	2, 3	+125°C, -55°C	-125	125	nA
Common Mode Range	+CMR	V+ = +3V, V- = -27V	1	+25°C	+12	-	V
			2, 3	+125°C, -55°C	+12	•	V
	-CMR	V+ = +27V, V- = -3V	1	+25°C	-	-12	V
	L		2, 3	+125°C, -55°C	·	-12	٧
Large Signal Voltage Gain		$V_{OUT} = 0V$ and +10V, $R_L = 2k\Omega$	4	+25°C	100	-	kV/V
			5, 6	+125°C, -55°C	100		kV/V
		$V_{OUT} = 0V$ and -10V, $R_L = 2k\Omega$	4	+25°C	100	-	kV/V
			5, 6	+125°C, -55°C	100	-	kV/V
Common Mode Rejection Ratio	+CMRR $\Delta V_{CM} = +5V$ , $V + = +10V$ , $V - = -20V$ , $V_{OUT} = -5V$		1	+25°C	86		dΒ
			2, 3	+125°C, -55°C	86	-	dB
	-CMRR $\Delta V_{CM} = -5V$ ,	1	+25°C	86	-	dB	
		V+ = +20V, V- = -10V, V <sub>OUT</sub> = +5V	2, 3	+125°C, -55°C	86		dB

## Specifications HA-5102/883

#### TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS (Continued)

Device Tested at:  $V_{SUPPLY}$  = ±15V,  $R_{SOURCE}$  = 100 $\Omega$ ,  $R_{LOAD}$  = 500k $\Omega$ ,  $V_{OUT}$  = 0V, Unless Otherwise Specified.

	SYMBOL	CONDITIONS	GROUP A SUBGROUPS	TEMPERATURE	LIMITS		
PARAMETERS					MIN	МАХ	UNITS
Output Voltage Swing	+V <sub>OUT1</sub>	$R_L = 2k\Omega$	1	+25°C	10	-	٧
			2, 3	+125°C, -55°C	10	•	٧
	-V <sub>OUT1</sub>	R <sub>L</sub> ≈ 2kΩ	1	+25°C	-	-10	٧
			2, 3	+125°C, -55°C	•	-10	V
	+V <sub>OUT2</sub>	$R_L = 10k\Omega$	1	+25°C	12		٧
			2, 3	+125°C, -55°C	12	-	V
	-V <sub>OUT2</sub>	$R_L = 10k\Omega$	1	+25°C	•	-12	٧
			2, 3	+125°C, -55°C	-	-12	٧
Output Current	+l <sub>out</sub>	V <sub>OUT</sub> = -5V	1	+25°C	10	-	mA
			2, 3	+125°C, -55°C	10		mA
	-l <sub>out</sub>	V <sub>OUT</sub> = +5V	1	+25°C	•	-10	mA
			2, 3	+125°C, -55°C		-10	mA
Quiescent Power Supply Current	+lcc	$V_{OUT} = 0V$ , $I_{OUT} = 0mA$	1	+25°C	•	5.0	mA
			2, 3	+125°C, -55°C	-	6.0	mA
	-lcc	V <sub>OUT</sub> = 0V, I <sub>OUT</sub> = 0mA	1	+25°C	-5.0	•	mA
			2, 3	+125°C, -55°C	-6.0	-	mA
Power Supply Rejection Ratio	+PSRR	$\Delta V_{SUP} = 10V$ ,	1	+25°C	86	-	₫B
		V+ = +10V, V- = -15V V+ = +20V, V- = -15V	2, 3	+125°C, -55°C	86	-	dB
	-PSRR	$\Delta V_{SUP} = 10V$ ,	1	+25°C	86	-	dB
		V+ = +15V, V- = -10V V+ = +15V, V- = -20V	2, 3	+125°C, -55°C	86	-	dB

#### TABLE 2. AC ELECTRICAL PERFORMANCE CHARACTERISTICS

Device Tested at:  $V_{SUPPLY} = \pm 15V$ ,  $H_{SOURCE} = 50\Omega$ ,  $H_{LOAD} = 2k\Omega$ ,  $C_{LOAD} = 50pF$ ,  $A_{VCL} = +1V/V$ , Unless Otherwise Specified.

PARAMETERS	SYMBOL	CONDITIONS	GROUP A SUBGROUPS	TEMPERATURE	LIMITS		
					MIN	MAX	UNITS
Slew Rate	+SR	V <sub>OUT</sub> = -3V to +3V	4	+25°C	1	-	V/µs
	-SR	V <sub>OUT</sub> = +3V to -3V	4	+25°C	1	-	V/µs
Rise and Fall Time	TR	$V_{OUT} = 0 \text{ to } +200\text{mV}$ $10\% \le T_{\text{R}} \le 90\%$	4	+25°C	-	200	ns
	T <sub>F</sub>	$V_{OUT} = 0 \text{ to -200mV}$ $10\% \le T_F \le 90\%$	4	+25°C	-	200	ns
Overshoot	+OS	V <sub>OUT</sub> = 0 to +200mV	4	+25°C	-	35	%
	-os	V <sub>OUT</sub> = 0 to -200mV	4	+25°C		35	%

#### Specifications HA-5102/883

#### **TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS**

Device Characterized at: V<sub>SUPPLY</sub> = ±15V, R<sub>LOAD</sub> = 2kΩ, C<sub>LOAD</sub> = 50pF, A<sub>VCL</sub> = 1V/V, Unless Otherwise Specified.

PARAMETERS	SYMBOL	CONDITIONS	NOTES	TEMPERATURE	LIMITS		
					MIN	MAX	UNITS
Differential Input Resistance	R <sub>IN</sub>	V <sub>CM</sub> = 0V	1	+25°C	250		kΩ
Input Noise Voltage Density	E <sub>N</sub>	$H_S = 20\Omega,$ $f_O = 1000Hz$	1	+25°C	•	6	nV/√Hz
Input Noise Current Density	I <sub>N</sub>	$R_S = 2M\Omega$ , $f_O = 1000Hz$	1	+25°C	•	3	pA∕√Hz
Full Power Bandwidth	FPBW	V <sub>PEAK</sub> = 10V	1, 2	+25°C	16	-	kHz
Minimum Closed Loop Stable Gain	CLSG	$R_L = 2k\Omega$ , $C_L = 50pF$	1	-55°C to +125°C	+1	-	V/V
Output Resistance	R <sub>OUT</sub>	Open Loop	1	+25°C	•	360	Ω
Quiescent Power Consumption	PC	V <sub>OUT</sub> = 0V, I <sub>OUT</sub> = 0mA	1, 3	-55°C to +125°C	-	180	mW
Channel Separation	cs	R <sub>S</sub> = 1kΩ, A <sub>VCL</sub> = 100V/V, V <sub>IN</sub> = 100mV <sub>PEAK</sub> at 10kHz Referred to Input	1	+25°C	60	-	dΒ

#### NOTES:

- Parameters listed in Table 3 are controlled via design or process parameters and are not directly tested at final production. These parameters are lab characterized upon initial design release, or upon design changes. These parameters are guaranteed by characterization based upon data from multiple production runs which reflect lot to lot and within lot variation.
- 2. Full Power Bandwidth guarantee based on Slew Rate measurement using FPBW = Slew Rate/( $2\pi V_{PEAK}$ ).
- 3. Quiescent Power Consumption based upon Quiescent Supply Current test maximum. (No load on outputs.).

**TABLE 4. ELECTRICAL TEST REQUIREMENTS** 

MIL-STD-883 TEST REQUIREMENTS	SUBGROUPS (SEE TABLES 1 AND 2)			
Interim Electrical Parameters (Pre Burn-In)	1			
Final Electrical Test Parameters	1 (Note 1), 2, 3, 4, 5, 6			
Group A Test Requirements	1, 2, 3, 4, 5, 6			
Groups C and D Endpoints	1			

#### NOTE:

PDA applies to Subgroup 1 only.

#### Die Characteristics

#### **DIE DIMENSIONS:**

98.4 x 67.3 x 19 mils  $\pm$  1 mils 2500 x 1710 x 483 $\mu$ m  $\pm$  25.4 $\mu$ m

#### **METALLIZATION:**

Type: Al, 1% Cu Thickness: 16kÅ ± 2kÅ

#### **GLASSIVATION:**

Type: Nitride (Si3N4) over Silox (SiO2, 5% Phos.) Silox Thickness: 12kÅ ± 2kÅ

Nitride Thickness: 3.5kÅ ± 1.5kÅ

WORST CASE CURRENT DENSITY:
1.43 x 10<sup>5</sup>A/cm<sup>2</sup> at 10mA

## SUBSTRATE POTENTIAL (Powered Up):

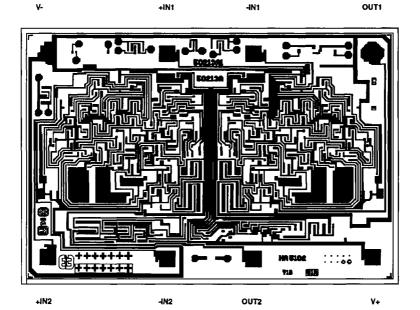
Unbiased

**TRANSISTOR COUNT: 93** 

PROCESS: Bipolar Dielectric Isolation

#### Metallization Mask Layout

HA-5102/883



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